

## Description

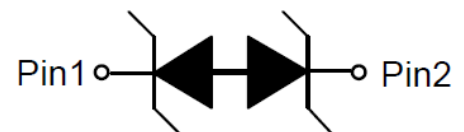
The XE2F3V3B is a bi-directional ESD protection diode designed to protect sensitive electronic components which are connected to low speed data lines and control lines from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lightning. The XE2F3V3B may be used to provide ESD protection up to  $\pm 30\text{kV}$  (contact and air discharge) according to IEC61000-4-2, and withstand peak pulse current up to 10A (8/20 $\mu\text{s}$ ) according to IEC61000-4-5.

The XE2F3V3B is available in DFN1006-2L package. Standard products are Pb-free and Halogen-free.

<http://www.xihangsemi.com>



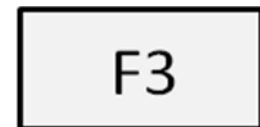
## DFN1006-2L (Bottom View)



## Circuit Diagram

## Features

- ◆ Working voltage: 3.3V
- ◆ DFN1006-2L Package
- ◆ Transient protection for data lines to IEC 61000-4-2 (ESD)  $\pm 30\text{kV}$  (air),  $\pm 30\text{kV}$  (contact)
- ◆ IEC 61000-4-5 (Surge) 10A (8/20 $\mu\text{s}$ )
- ◆ Low leakage current
- ◆ Low clamping voltage
- ◆ Solid-state silicon-avalanche technology



## Marking (Top View)

## Order Information

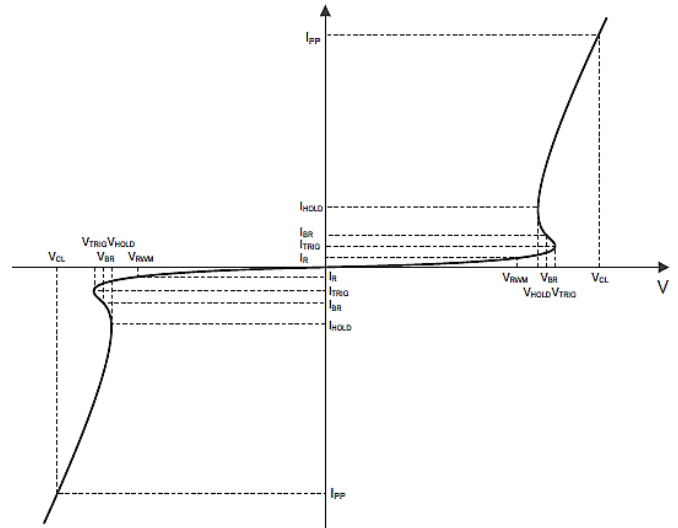
Device	Package	Shipping
XE2F3V3B	DFN1006-2L	10000/Tape&Reel

## Applications

- ◆ Personal digital assistants (PDA's)
- ◆ Notebooks, Desktops, and Servers
- ◆ Cell phone Handsets and Accessories
- ◆ Portable Electronics
- ◆ Peripherals

## Definitions of electrical characteristics

Symbol	Parameter
$V_{RWM}$	Reverse Stand-off Voltage
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Reverse Breakdown Voltage @ $I_T$
$I_{BR}$	Reverse Breakdown Current
$I_{PP}$	Reverse Peak Pulse Current
$V_{CL}$	Clamping Voltage @ $I_{PP}$
$V_{TRIG}$	Reverse Trigger Voltage
$I_{TRIG}$	Reverse Trigger Current
$V_{HOLD}$	Reverse Holding Voltage
$I_{HOLD}$	Reverse Holding Current



## Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ( $t_p = 8/20\mu S$ )	$P_{PK}$	85	W
Peak Pulse Current ( $t_p = 8/20\mu S$ )	$I_{pp}$	10	A
ESD according to IEC61000-4-2 air discharge	$V_{ESD}$	$\pm 30$	kV
ESD according to IEC61000-4-2 contact discharge		$\pm 30$	kV
Lead Soldering Temperature	$T_L$	260 (10 sec)	$^{\circ}C$
Operating Temperature	$T_{OP}$	-55 to +125	$^{\circ}C$
Storage Temperature	$T_{STG}$	-55 to +150	$^{\circ}C$

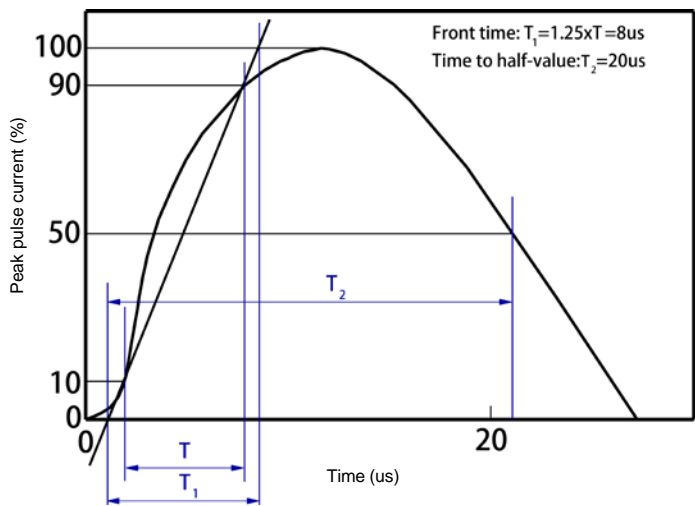
## Electrical Characteristics ( $T_a=25^{\circ}C$ , unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Reverse Stand-off Voltage	$V_{RWM}$				$\pm 3.3$	V
Reverse Leakage Current	$I_R$	$V_{RWM}=3.3V$			100	nA
Reverse Breakdown Voltage	$V_{BR}$	$I_T=1mA$	3.5	4.1	4.5	V
Reverse Holding Voltage	$V_{Hold}$	$I_{Hold}=50mA$	3.5	4.1	4.5	V
Clamping Voltage <sup>1)</sup>	$V_{CL}$	$I_{PP}=5A$ $t_p = 8/20\mu s$			6	V
		$I_{PP}=10A$ $t_p = 8/20\mu s$			8.5	V
Junction Capacitance	$C_j$	$V_R=0V$ $f = 1MHz$		13	15	pF

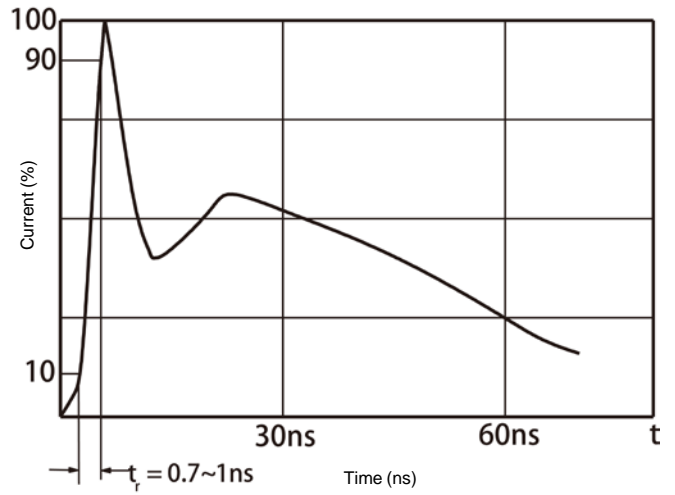
Notes:

1) Non-repetitive current pulse, according to IEC61000-4-5.

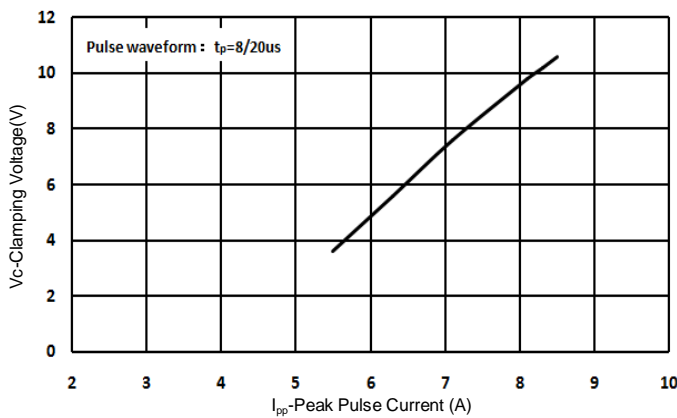
Typical Characteristics (Ta=25°C, unless otherwise noted)



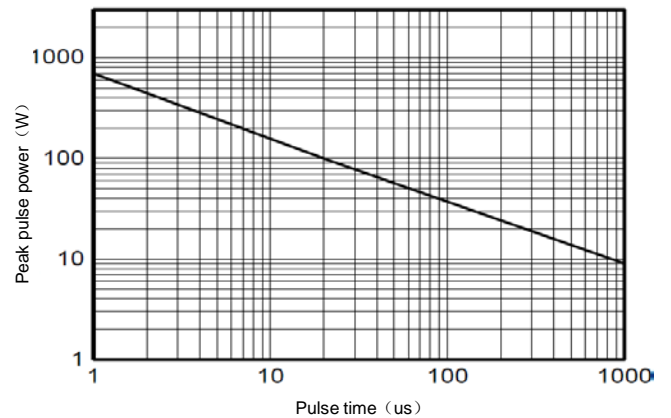
8/20 us waveform per IEC61000-4-5



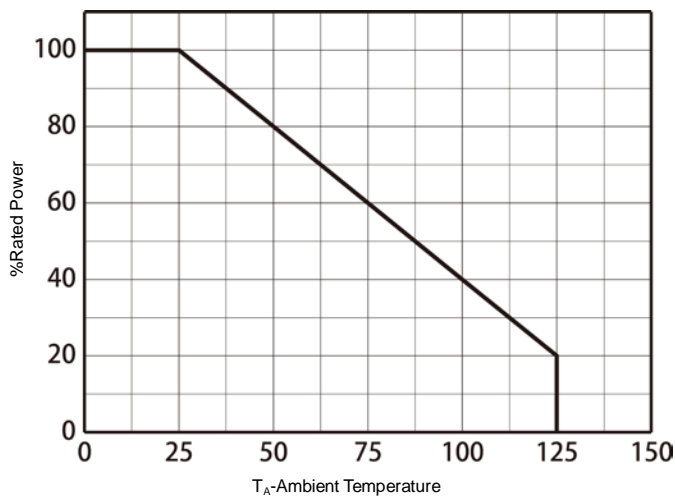
Contact discharge current waveform per IEC61000-4-2



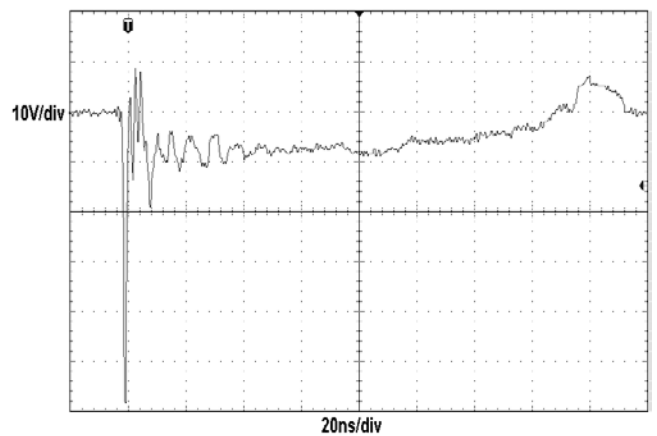
Clamping voltage vs. Peak pulse current



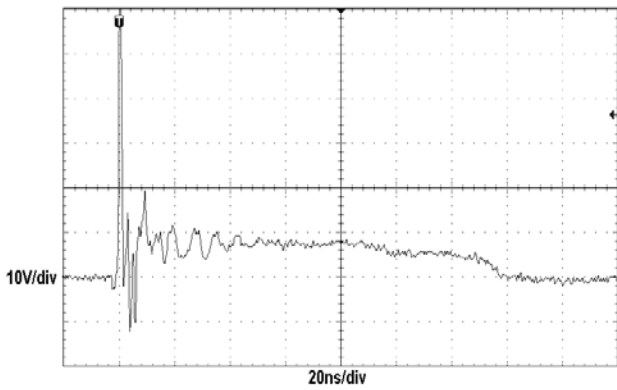
Non-repetitive peak pulse power vs. Pulse time



Power derating vs. Ambient temperature

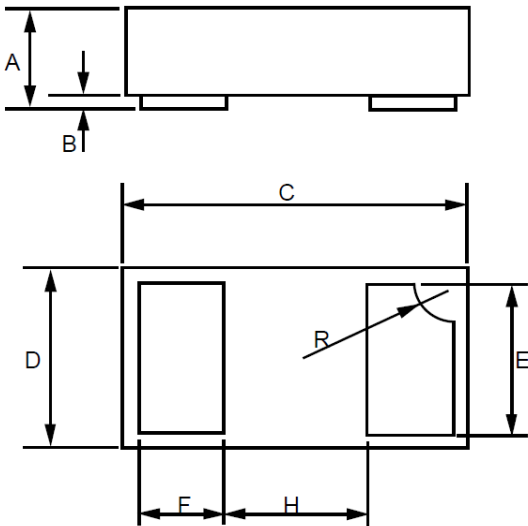


ESD Clamping(+8kV Contact Discharge)



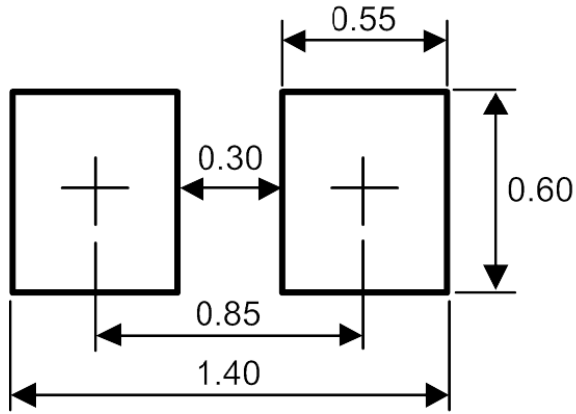
ESD Clamping(-8kV Contact Discharge)

Package Outline Dimensions (DFN1006-2L)



Dim	Inches		Millimeters	
	MIN	MAX	MIN	MAX
A	0.018	0.020	0.46	0.51
B	0.000	0.002	0	0.05
C	0.037	0.041	0.95	1.05
D	0.022	0.025	0.55	0.65
E	0.017	0.021	0.45	0.55
F	0.008	0.012	0.20	0.30
H	0.015Typ.		0.40Typ	
R	0.001	0.005	0.05	0.15

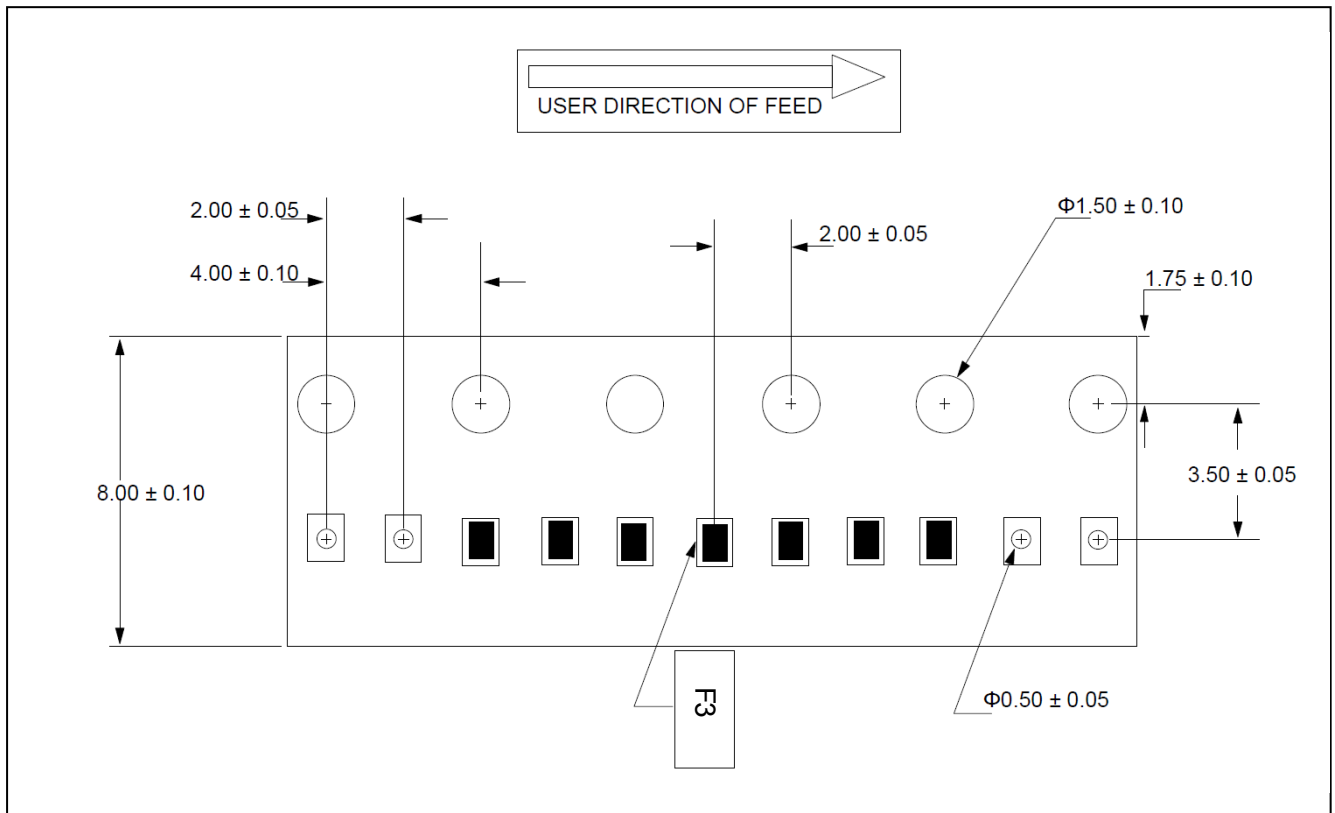
**Recommend Land Pattern (Unit: mm)**



Note:

This recommended land pattern is for reference purpose only.

**Load with information**



Unit: mm